## NSN 5961-00-855-3746



Transistor - Page 1 of 2 View Online at https://aerobasegroup.com/nsn/5961-00-855-3746 **Inclosure Material:** Metal **Overall Length:** 0.550 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** 0.875 inches **Thread Size:** 0.500 inches **Semiconductor Material:** Germanium Voltage Rating In Volts Per Characteristic: -60.0 collector to base voltage, dc and -20.0 emitter to base voltage, dc **Power Rating Per Characteristic:** 20.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 100.0 degrees celsius junction **Special Features:** Junction pattern arrangement: pnp **Test Data Document:** 81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.). **Thread Series Designator:** Unf **Terminal Type And Quantity:** 3 uninsulated wire lead **Specification Data:** 81349-mil-s-19500/137 government specification Shelf Life: N/a

No

**Unit Of Measure:** 

**Demilitarization:** 

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